



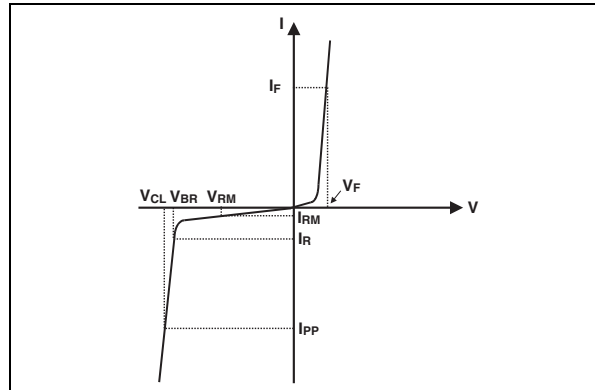
# EMIF10-LCD01C1

**Table 2: Absolute Maximum Ratings** ( $T_{amb} = 25^{\circ}\text{C}$ )

| Symbol    | Parameter                   | Value       | Unit               |
|-----------|-----------------------------|-------------|--------------------|
| $T_j$     | Junction temperature        | 125         | $^{\circ}\text{C}$ |
| $T_{op}$  | Operating temperature range | -40 to + 85 | $^{\circ}\text{C}$ |
| $T_{stg}$ | Storage temperature range   | -55 to +150 | $^{\circ}\text{C}$ |

**Table 3: Electrical Characteristics** ( $T_{amb} = 25^{\circ}\text{C}$ )

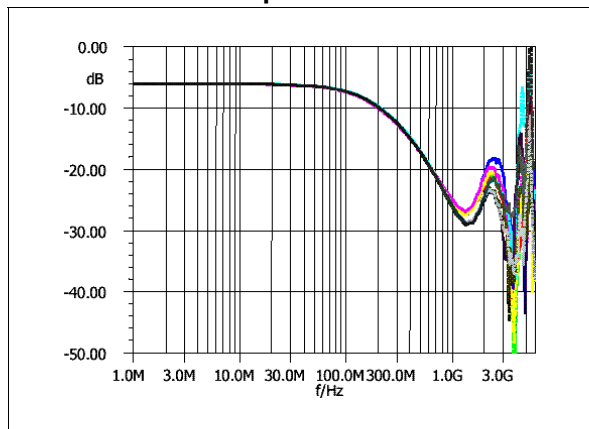
| Symbol    | Parameter                                |
|-----------|--|
| $V_{BR}$  | Breakdown voltage                        |
| $I_{RM}$  | Leakage current @ $V_{RM}$               |
| $V_{RM}$  | Stand-off voltage                        |
| $V_{CL}$  | Clamping voltage                         |
| $R_d$     | Dynamic resistance                       |
| $I_{PP}$  | Peak pulse current                       |
| $R_{I/O}$ | Series resistance between Input & Output |
| Cline     | Input capacitance per line               |



| Symbol    | Test conditions  | Min. | Typ.  | Max. | Unit     |
|-----------|--|------|-------|------|----------|
| $V_{BR}$  | $I_R = 1 \text{ mA}$   | 6    | 8     | 10   | V        |
| $I_{RM}$  | $V_{RM} = 3\text{V}$   |      |       | 500  | nA       |
| $R_{I/O}$ |  | 90   | 100   | 110  | $\Omega$ |
| Cline     | @ 0V bias  |      | 28    | 35   | pF       |
| Rt / Ft   | Induced rise and fall time 10-90% at 26 MHz frequency signal $V = 1.9 \text{ V}$ (Rt / Ft input 1 ns, 50 $\Omega$ impedance generator) |      | 8 (1) |      | ns       |

(1) guaranteed by design

**Figure 3: S21(dB) all lines attenuation measurement and Aploc simulation**



**Figure 4: Analog cross talk measurements**

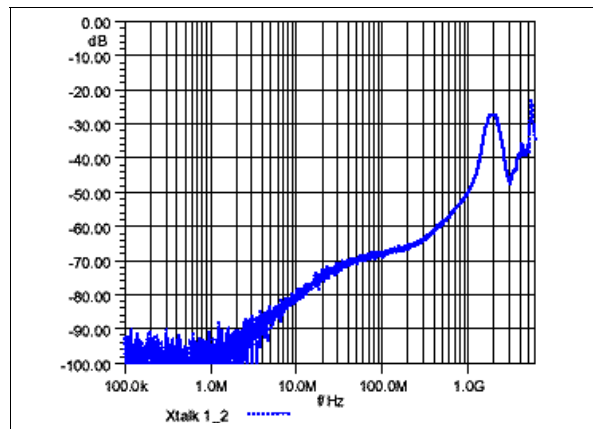


Figure 5: ESD response to IEC61000-4-2 (+15kV air discharge) on one input and on one output

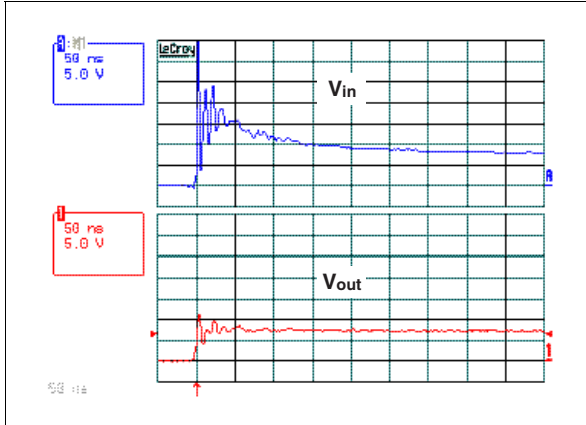


Figure 6: ESD response to IEC61000-4-2 (-15kV air discharge) on one input and on one output

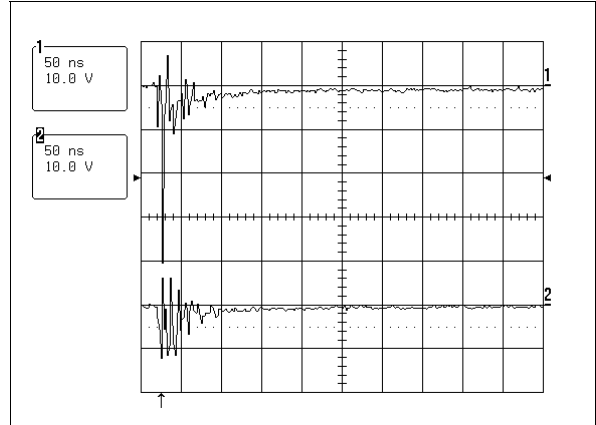


Figure 7: Line capacitance versus applied voltage

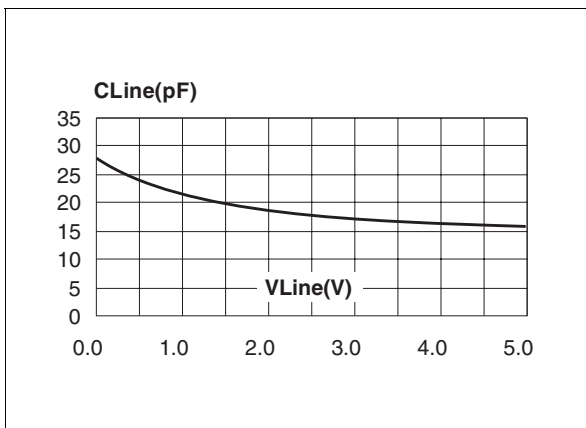


Figure 8: Rise time 10-90% measurements with 1.9V signal at 26 MHz frequency (50Ω generator)

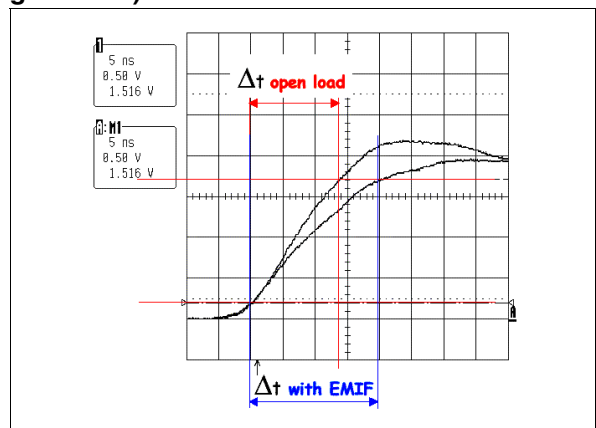


Figure 9: Fall time 10-90% measurements with 1.9V signal at 26 MHz frequency (50Ω generator)

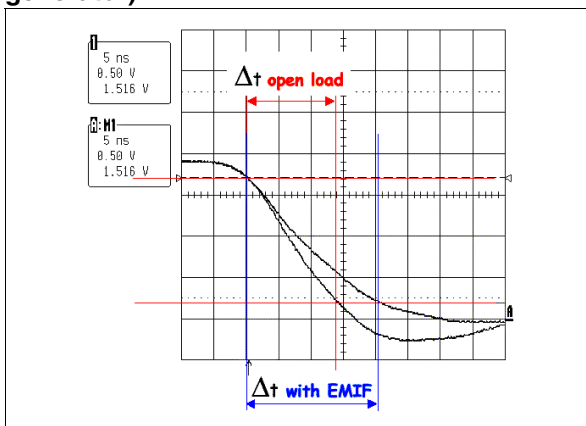


Figure 10: Aplac model

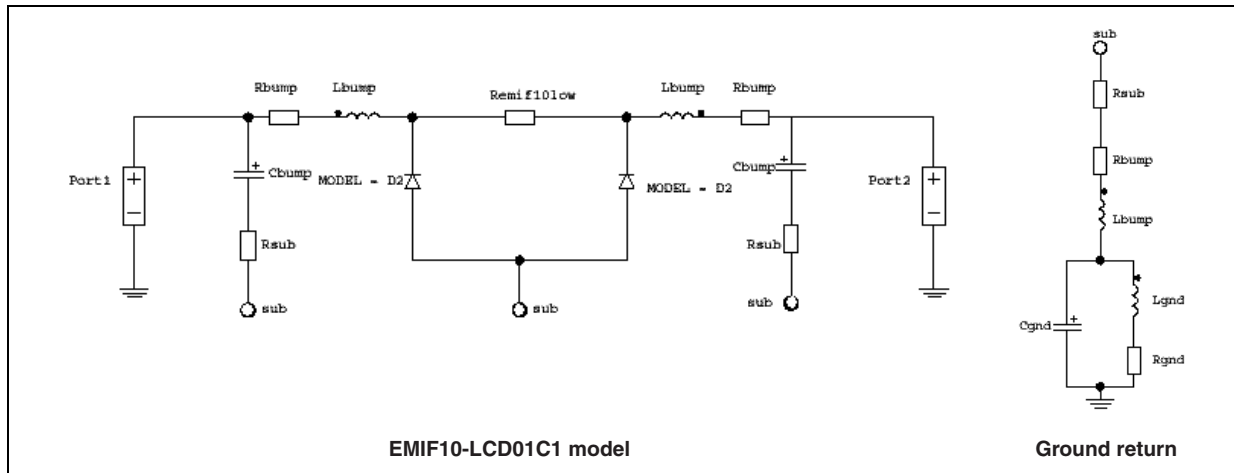


Figure 11: Aplac parameters

|                             |                  |
|-----------------------------|------------------|
| ZRZ structure               |                  |
| aplacvar Remif10low 100     | BV = 7           |
| aplacvar Cemif10flow 17.5pF | CJO = Cemif10low |
| Bumps                       | IBV = 1u         |
| aplacvar Lbump 50pH         | IKF = 1000       |
| aplacvar Rbump 20m          | IS = 10f         |
| aplacvar Cbump 1.5pF        | ISR = 100p       |
| Bulk                        | N = 1            |
| aplacvar Rsub 100m          | M = 0.3333       |
| Gnd connections             | RS = 0.015       |
| aplacvar Rgnd 100m          | VJ = 0.6         |
| aplacvar Lgnd 200pH         | TT = 50n         |
| aplacvar Cgnd 0.15pF        |                  |

Figure 12: Order Code

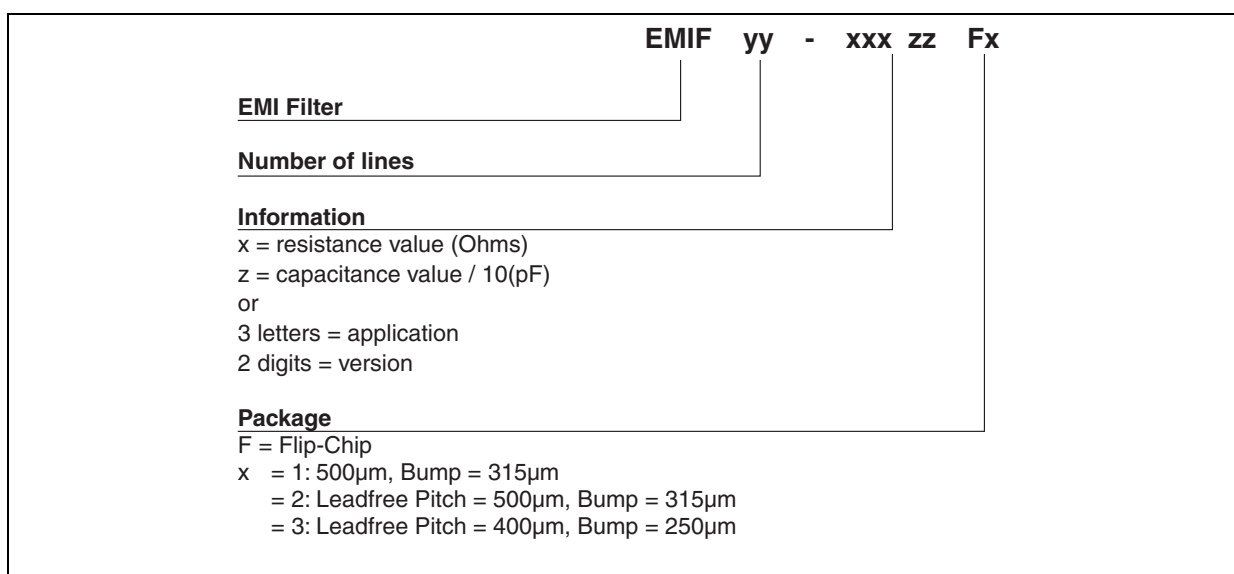


Figure 13: FLIP-CHIP Package Mechanical Data

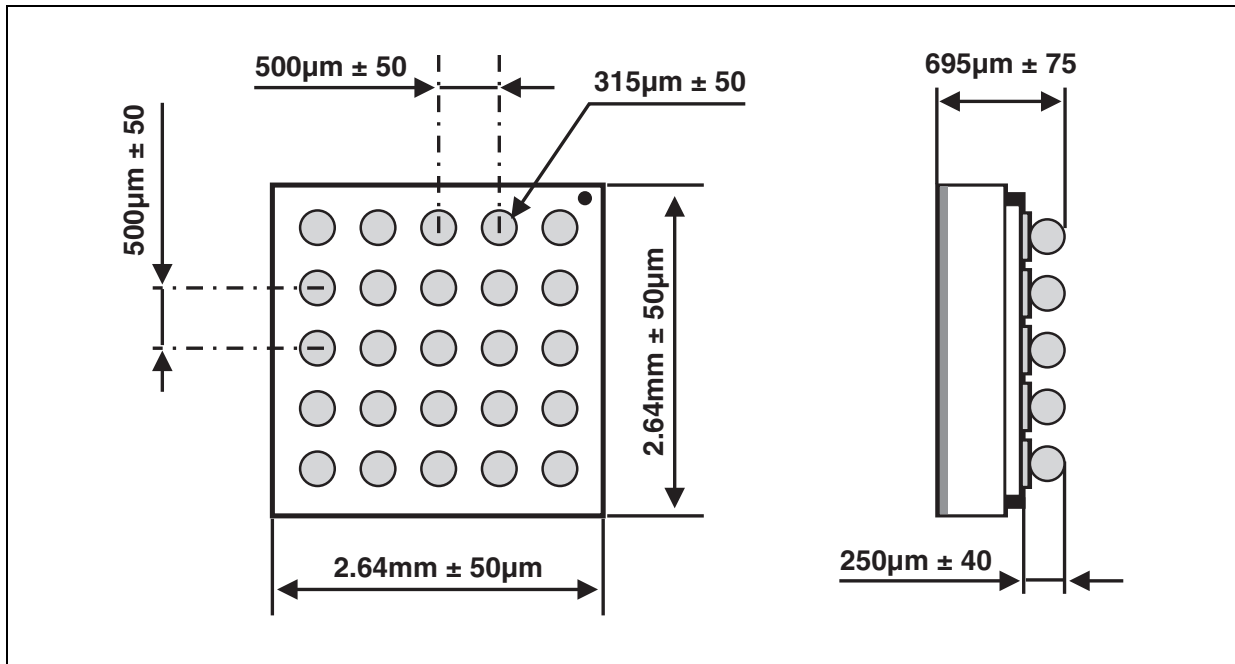


Figure 14: Foot Print Recommendations

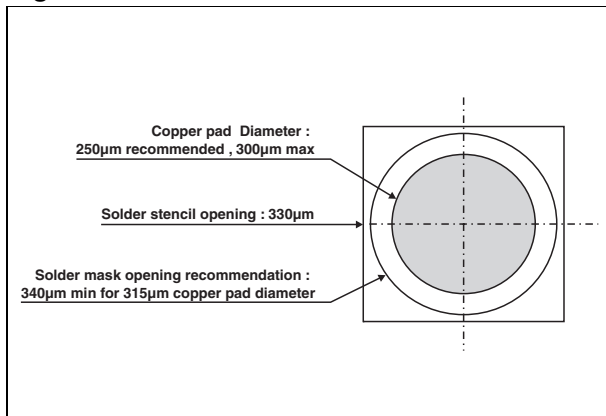


Figure 15: Marking

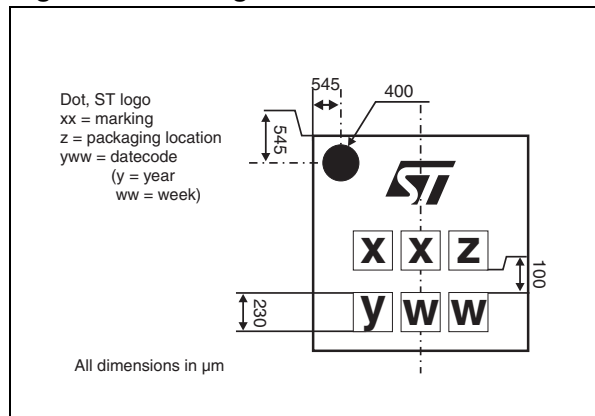


Figure 16: FLIP-CHIP Tape and Reel Specification

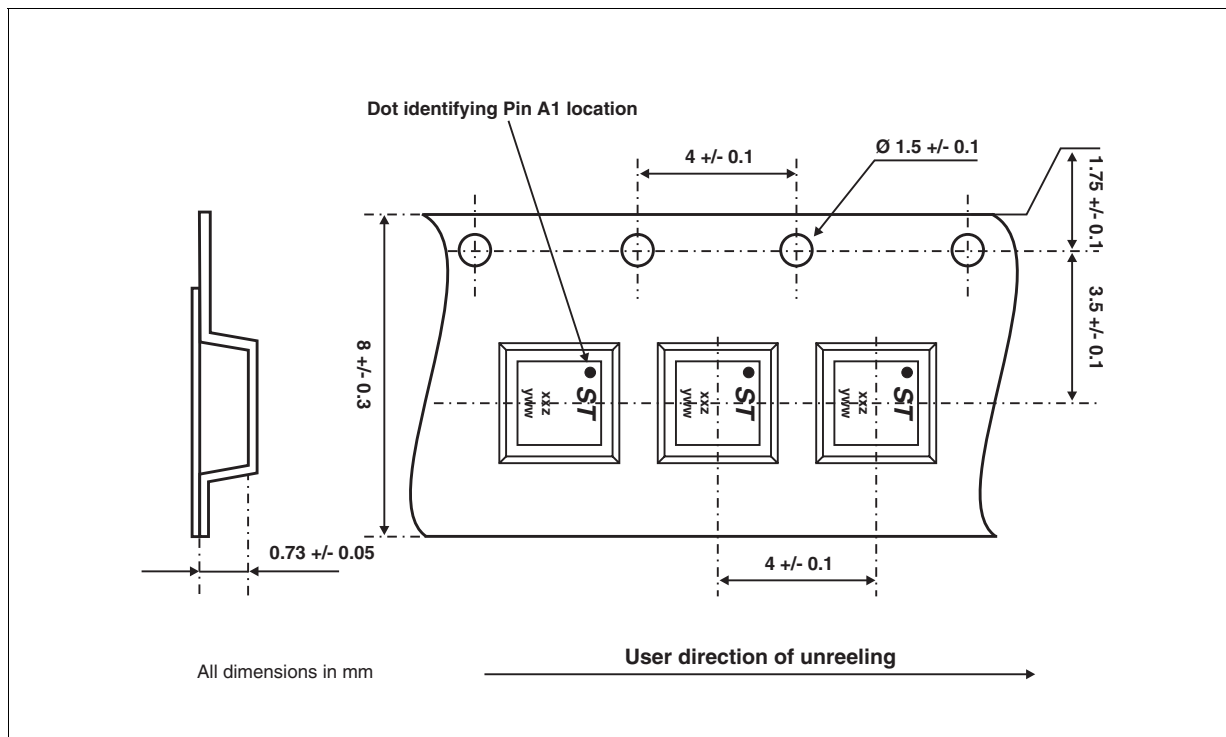


Table 4: Ordering Information

| Part Number    | Marking | Package   | Weight | Base qty | Delivery mode    |
|----------------|---------|-----------|--------|----------|------------------|
| EMIF10-LCD01C1 | FL      | Flip-Chip | 9.3 mg | 5000     | Tape & reel (7") |

**Note:** Further packing information available in the application notes  
 - AN1235: "Flip-Chip: Package description and recommendations for use"  
 - AN1751: "EMI Filters: Recommendations and measurements"

Table 5: Revision History

| Date        | Revision | Description of Changes                                |
|-------------|----------|---|
| Sep-2004    | 1        | First issue   |
| 09-Jun-2005 | 2        | Modified C <sub>line</sub> Typical and Maximum values |

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics.  
All other names are the property of their respective owners

© 2005 STMicroelectronics - All rights reserved

**STMicroelectronics group of companies**

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -  
Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America  
[www.st.com](http://www.st.com)

